NSN 5961-01-245-6102

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-245-6102
Inclosure Material:
Metal
Overall Length:
2.637 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-83
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 1.031 inches and 1.063 inches
Thread Size:
0.469 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
120.0 repetitive peak off-state voltage and 3.0 gate trigger voltage, instantaneous
Current Rating Per Characteristic:
1000.00 amperes forward current, total rms watts and 6.50 milliamperes forward current, total rms
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Thread Series Designator:
Unc
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0